









SN74LVC257A-Q1

SCAS709C - SEPTEMBER 2003 - REVISED MAY 2024

SN74LVC257A-Q1 Automotive Quadruple 2-Line To 1-Line Data Selector/Multiplexer With 3-State Outputs

1 Features

- Qualified for automotive applications
- ESD protection exceeds 2000V per MIL-STD-883, method 3015
- Operates from 2V to 3.6V
- Inputs accept voltages to 5.5V
- Max t_{pd} of 4.6ns at 3.3V
- Typical V_{OLP} (output ground bounce) < 0.8V at V_{CC} $= 3.3V, T_A = 25^{\circ}C$
- Typical V_{OHV} (output V_{OH} undershoot) > 2V at V_{CC} $= 3.3V, T_A = 25$ °C

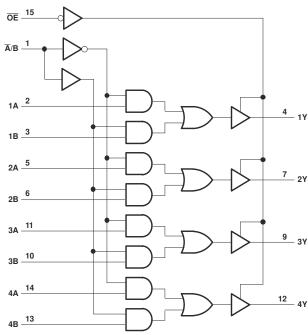
2 Description

The SN74LVC257A quadruple 2-line to 1-line data selector/multiplexer is designed for 2.7V to 3.6V V_{CC} operation.

Package Information

PART NUMBER	PACKAGE ⁽¹⁾	PACKAGE SIZE(2)	BODY SIZE(3)				
	BQB (WQFN, 16)	3.5mm × 2.5mm	3.5mm × 2.5mm				
SN74LVC257A-Q1	D (SOIC, 16)	9.90 mm × 6mm	9.90 mm × 3.90 mm				
	PW (TSSOP, 16)	5.00 mm × 6.4mm	5.00 mm × 4.40 mm				

- (1) For more information, see Mechanical, Packaging, and Orderable Information.
- The package size (length × width) is a nominal value and (2)includes pins, where applicable.
- (3)The body size (length × width) is a nominal value and does not include pins.



Logic Diagram (Positive Logic)



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3 Pin Configuration and Functions

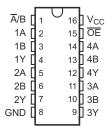


Figure 3-1. D or PW Package, 16-Pin SOIC or TSSOP (Top View)

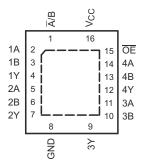


Figure 3-2. BQB Package, 16-Pin WQFN with Exposed Thermal Pad (Top View)

Table 3-1. Pin Functions

	PIN		
NAME	SOIC, TSSOP, or WQFN	1/0	DESCRIPTION
Ā/B	1	I	Select Pin, Low selects A, High selects B
1A	2	I/O	Multiplexer Signal Input
1B	3	I/O	Multiplexer Signal Input
1Y	4	I/O	Multiplexer Output
2A	5	I/O	Multiplexer Signal Input
2B	6	I/O	Multiplexer Signal Input
2Y	7	I/O	Multiplexer Output
3A	11	I/O	Multiplexer Signal Input
3B	10	I/O	Multiplexer Signal Input
3Y	9	I/O	Multiplexer Output
4A	14	I/O	Multiplexer Signal Input
4B	13	I/O	Multiplexer Signal Input
4Y	12	I/O	Multiplexer Output
GND	8	_	Ground
NC ⁽¹⁾	_	_	No connect
ŌĒ	15	I/O	Active low Output enable
V _{CC}	16	_	Power pin

(1) NC – no internal connection



4 Specifications

4.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CC}	Supply voltage range		-0.5	6.5	V
VI	Input voltage range ⁽¹⁾		-0.5	6.5	V
Vo	Output voltage range ⁽¹⁾ (2)		-0.5	V _{CC} + 0.5	V
I _{IK}	Input clamp current	V _I < 0		-50	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
Io	Continuous output current			±50	mA
	Continuous current through V _{CC} or GND			±100	mA
T _{stg}	Storage temperature range		-65	150	°C

⁽¹⁾ The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

4.2 ESD Ratings

			VALUE	UNIT
V _{(E}	Electrostatic SD) discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾	±2000	V

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

4.3 Recommended Operating Conditions

over recommended operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V	Cumply voltage	Operating	2	3.6	V
V _{CC}	Supply voltage	Data retention only	1.5		V
V _{IH}	High-level input voltage	V _{CC} = 2.7 V to 3.6 V	2		V
V _{IL}	Low-level input voltage	V _{CC} = 2.7 V to 3.6 V		0.8	V
VI	Input voltage		0	5.5	V
Vo	Output voltage		0	V _{CC}	V
	High level output ourrent	V _{CC} = 2.7 V		-12	mA
Іон	High-level output current	$V_{CC} = 3 V$		-24	ША
	Low-level output current	$V_{CC} = 2.7 V$		12	mA
IOL	Low-level output current	V _{CC} = 3 V		24	ША
Δt/Δν	Input transition rise or fall rate			10	ns/V
T _A	Operating free-air temperature		-40	125	°C

4.4 Thermal Information

THERMAL METRIC(1)					
		BQB (WQFN)	D (SOIC)	PW (TSSOP)	UNIT
			16 PINS		
$R_{\theta JA}$	Junction-to-ambient thermal resistance	98.8	73	108	°C/W

⁽¹⁾ For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report, SPRA953.

Product Folder Links: SN74LVC257A-Q1

The value of V_{CC} is provided in the recommended operating conditions table.

4.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V _{CC}	MIN	TYP ⁽¹⁾	MAX	UNIT
	I _{OH} = -100 μA	2.7 V to 3.6 V	V _{CC} - 0.2			
V	I _{OH} = –12 mA	2.7 V	2.2			V
V _{OH}	10H12 111A	3 V	2.4			V
	I _{OH} = -24 mA	3 V	2.2			
	I _{OL} = 100 μA	2.7 V to 3.6 V			0.2	
V _{OL}	I _{OL} = 12 mA	2.7 V			0.4	V
	I _{OL} = 24 mA	3 V			0.55	
I _I	V _I = 5.5 V or GND	3.6 V			±5	μΑ
I _{OZ}	V _O = V _{CC} or GND	3.6 V			±15	μΑ
I _{CC}	$V_I = V_{CC}$ or GND, $I_O = 0$	3.6 V			10	μΑ
ΔI _{CC}	One input at $V_{CC} - 0.6 \text{ V}$, Other inputs at V_{CC} or GND	2.7 V to 3.6 V			500	μΑ
Ci	V _I = V _{CC} or GND	3.3 V		5		pF
Co	V _O = V _{CC} or GND	3.3 V		5		pF

⁽¹⁾ All typical values are at V_{CC} = 3.3 V, T_A = 25°C.

4.6 Switching Characteristics

over recommended operating free-air temperature range (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 2.7 V	V _{CC} = 3.3 V ± 0.3 V		UNIT
	(IIVF 01)	(001701)	MIN MAX	MIN	MAX	
+	A or B	Y	5.4	1	4.6	no
^L pd	Ā/B		7.5	1	6.4	ns
t _{en}	ŌĒ	Y	6.7	1	5.6	ns
t _{dis}	ŌĒ	Y	4.7	0.5	4.3	ns
t _{sk(o)}					1	ns

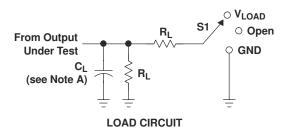
4.7 Operating Characteristics

 $T_A = 25^{\circ}C$

	PARAMETER	TEST CONDITIONS	V _{CC} = 2.5 V TYP	V _{CC} = 3.3 V TYP	UNIT
C_{pd}	Power dissipation capacitance	f = 10 MHz	14.5	15.5	pF

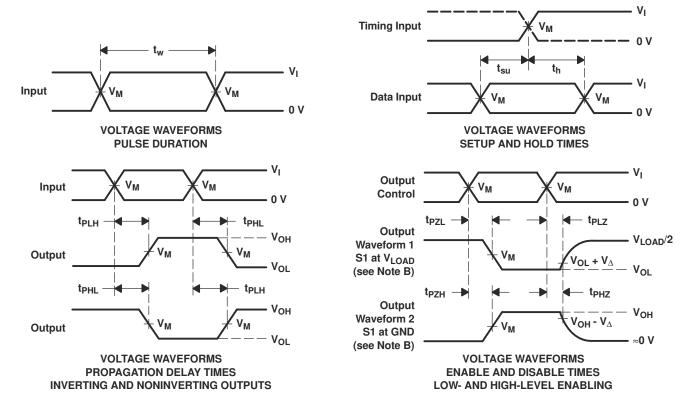


5 Parameter Measurement Information



TEST	S1
t _{PLH} /t _{PHL} t _{PLZ} /t _{PZL} t _{PHZ} /t _{PZH}	Open V _{LOAD} GND

		PUTS		V			.,
V _{CC}	VI	t _r /t _f	t _r /t _f V _M V _{LOA}		CL	RL	V_Δ
2.7 V	2.7 V	≤2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V
3.3 V \pm 0.3 V	2.7 V	≤2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V



- NOTES: A. C_I includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \ \Omega$.
 - D. The outputs are measured one at a time, with one transition per measurement.
 - E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
 - F. t_{PZL} and t_{PZH} are the same as t_{en} .
 - G. t_{PLH} and t_{PHL} are the same as t_{pd}.
 - H. All parameters and waveforms are not applicable to all devices.

Figure 5-1. Load Circuit and Voltage Waveforms

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6 Detailed Description

6.1 Overview

The device is designed to multiplex signals from 4-bit data sources to 4-output data lines in bus-organized systems. The 3-state outputs do not load the data lines when the output-enable (\overline{OE}) input is at a high logic level.

Inputs can be driven from either 3.3V or 5V devices. This feature allows the use of this device as a translator in a mixed 3.3V/5V system environment.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

6.2 Functional Block Diagram

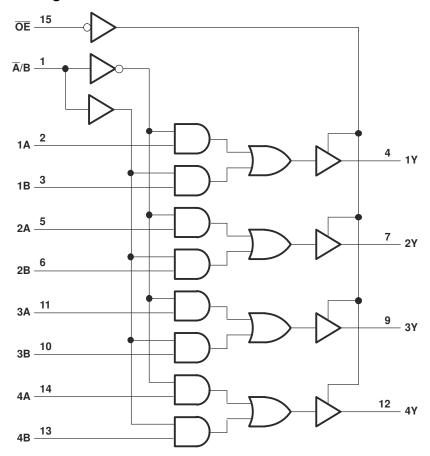


Figure 6-1. Logic Diagram (Positive Logic)



6.3 Device Functional Modes

Function Table lists the functional modes for the SN74LVC257A-Q1 devices.

Function Table

	OUTPUT			
ŌĒ	Ā/B	Α	В	Υ
Н	X	Х	Х	Z
L	L	L	Х	L
L	L	Н	X	Н
L	Н	X	L	L
L	Н	Χ	Н	Н



7 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

7.1 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the Section 4.3 table.

Each V_{CC} terminal must have a good bypass capacitor to prevent power disturbance. For devices with a single supply, a 0.1- μ F capacitor is recommended. If there are multiple V_{CC} terminals then 0.01- μ F or 0.022- μ F capacitors are recommended for each power terminal. It is ok to parallel multiple bypass capacitors to reject different frequencies of noise. Multiple bypass capacitors may be paralleled to reject different frequencies of noise. The bypass capacitor must be installed as close to the power terminal as possible for the best results.

7.2 Layout

7.2.1 Layout Guidelines

When using multiple bit logic devices, inputs must not float. In many cases, functions or parts of functions of digital logic devices are unused. Some examples are when only two inputs of a triple-input AND gate are used, or when only 3 of the 4-buffer gates are used. Such input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states.

Specified in Layout Example for the SN74LVC257A-Q1 are rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or V_{CC} , whichever makes more sense or is more convenient.

7.2.2 Layout Example

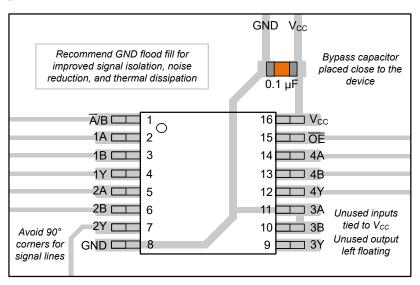


Figure 7-1. Example Layout for the SN74LVC257A-Q1



8 Device and Documentation Support

8.1 Documentation Support (Analog)

8.1.1 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 8-1. Related Links

PARTS	PRODUCT FOLD	ER SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY	
SN74LVC257A	Q1 Click here	Click here	Click here	Click here	Click here	

8.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

8.3 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

8.4 Trademarks

TI E2E[™] is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

8.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

8.6 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

9 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision B (February 2008) to Revision C (May 2024)

Page

- Added Package Information table, Pin Functions table, ESD Ratings table, Thermal Information table, Device Functional Modes, Application and Implementation section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information section

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10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS	Lead finish/	MSL rating/	Op temp (°C)	Part marking
	(1)	(2)			(3)	Ball material	Peak reflow		(6)
						(4)	(5)		
CLVC257AQPWRG4Q1	Active	Production	TSSOP (PW) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	L257AQ1
CLVC257AQPWRG4Q1.B	Active	Production	TSSOP (PW) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	L257AQ1
SN74LVC257ADRQ1	Active	Production	SOIC (D) 16	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC257AQ
SN74LVC257ADRQ1.A	Active	Production	SOIC (D) 16	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC257AQ
SN74LVC257APWRQ1	Active	Production	TSSOP (PW) 16	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC257Q
SN74LVC257APWRQ1.A	Active	Production	TSSOP (PW) 16	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC257Q
SN74LVC257AQDRG4Q1	Active	Production	SOIC (D) 16	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	L257AQ1
SN74LVC257AQDRG4Q1.B	Active	Production	SOIC (D) 16	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	L257AQ1
SN74LVC257AWBQBRQ1	Active	Production	WQFN (BQB) 16	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC257Q
SN74LVC257AWBQBRQ1.A	Active	Production	WQFN (BQB) 16	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC257Q

⁽¹⁾ Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.



PACKAGE OPTION ADDENDUM

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and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF SN74LVC257A-Q1:

Catalog : SN74LVC257A

● Enhanced Product: SN74LVC257A-EP

Military: SN54LVC257A

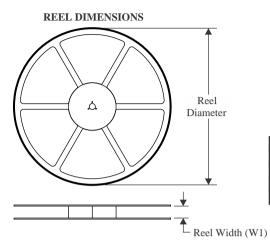
NOTE: Qualified Version Definitions:

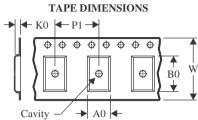
- Catalog TI's standard catalog product
- Enhanced Product Supports Defense, Aerospace and Medical Applications
- Military QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

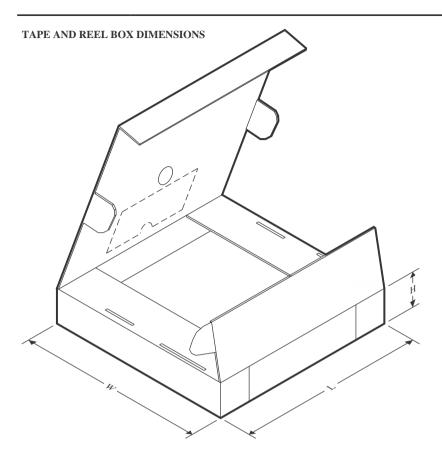
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CLVC257AQPWRG4Q1	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LVC257ADRQ1	SOIC	D	16	3000	330.0	12.4	3.75	3.75	1.15	8.0	12.0	Q1
SN74LVC257APWRQ1	TSSOP	PW	16	3000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LVC257AWBQBRQ1	WQFN	BQB	16	3000	180.0	12.4	2.8	3.8	1.2	4.0	12.0	Q1

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*All dimensions are nominal

7 til dillionorono di o mominar							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CLVC257AQPWRG4Q1	TSSOP	PW	16	2000	353.0	353.0	32.0
SN74LVC257ADRQ1	SOIC	D	16	3000	340.5	336.1	32.0
SN74LVC257APWRQ1	TSSOP	PW	16	3000	353.0	353.0	32.0
SN74LVC257AWBQBRQ1	WQFN	BQB	16	3000	210.0	185.0	35.0

D (R-PDS0-G16)

PLASTIC SMALL OUTLINE



NOTES:

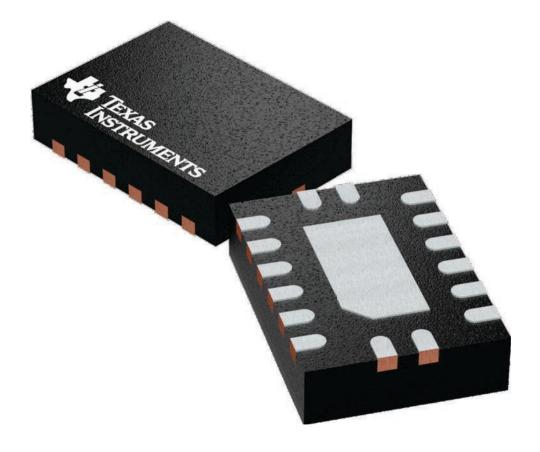
- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



2.5 x 3.5, 0.5 mm pitch

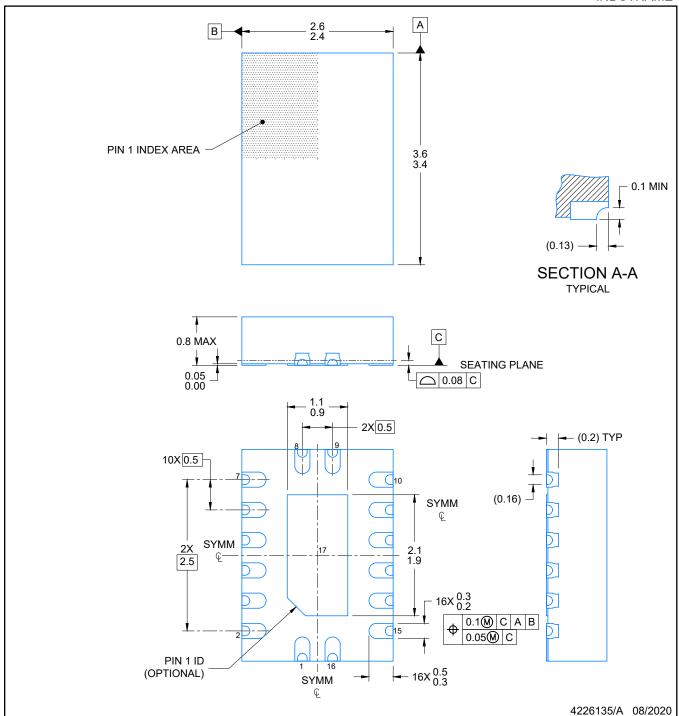
PLASTIC QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



INSTRUMENTS www.ti.com

INDSTNAME

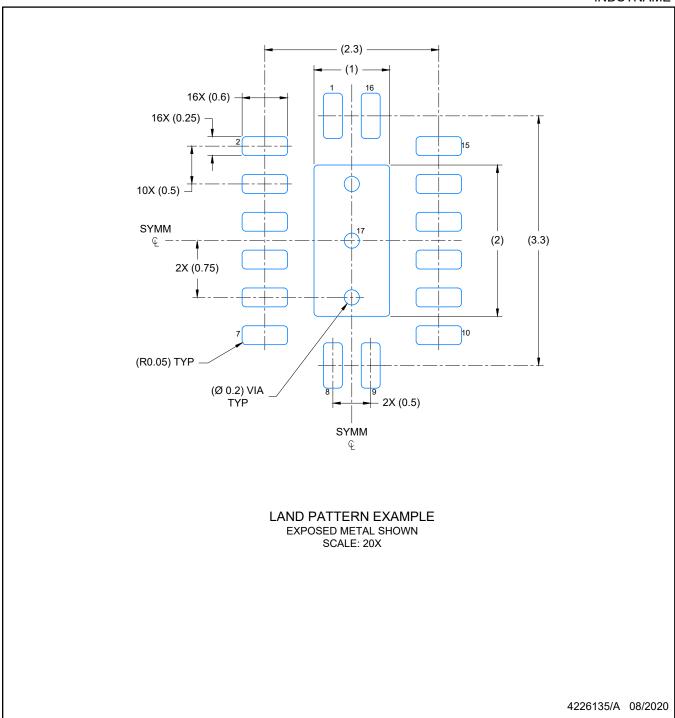


NOTES:

- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for optimal thermal and mechanical performance.



INDSTNAME

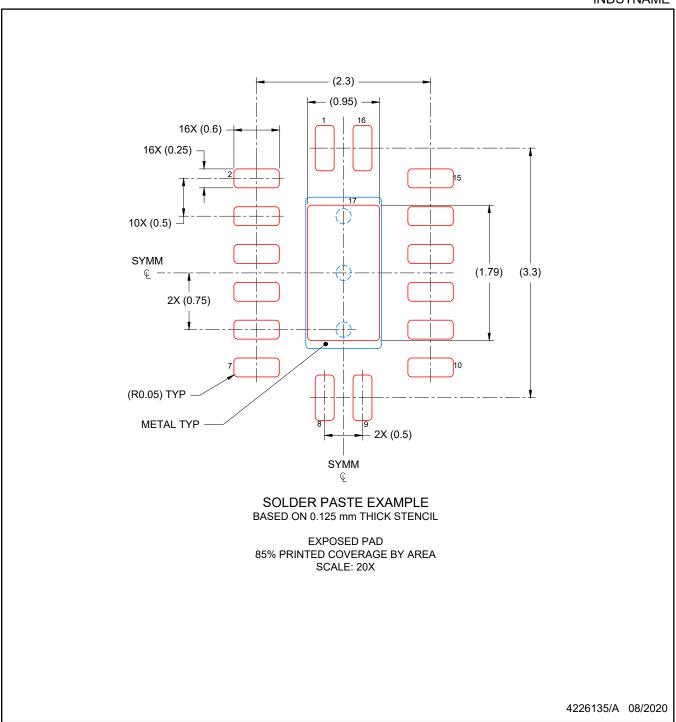


NOTES: (continued)

- 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- 5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



INDSTNAME



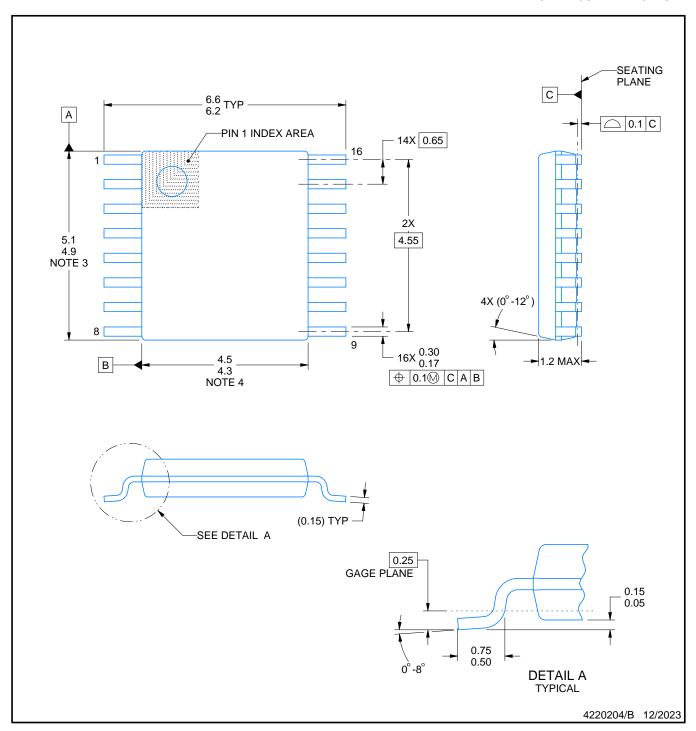
NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.





SMALL OUTLINE PACKAGE



NOTES:

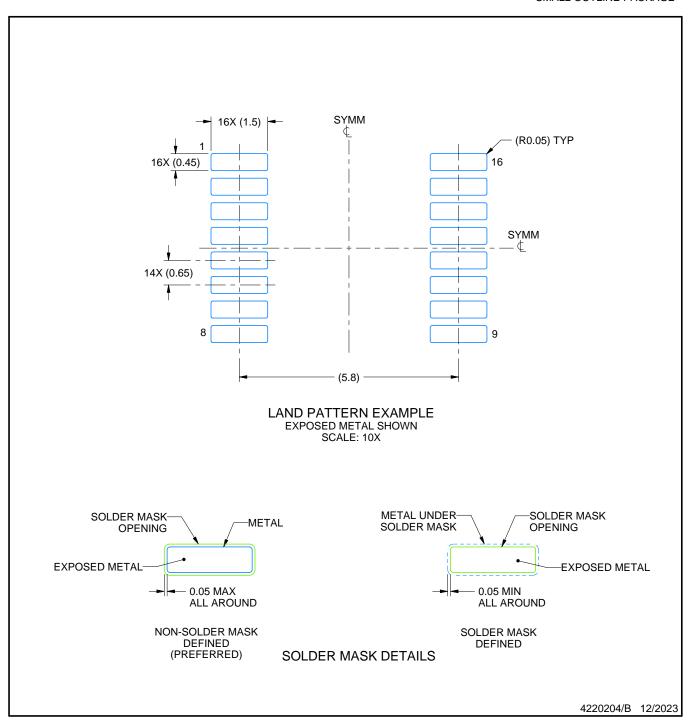
- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE

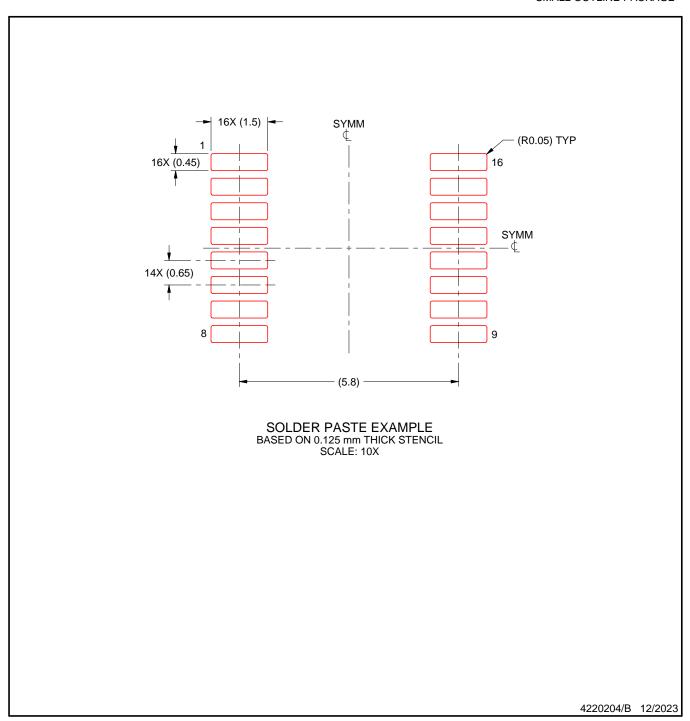


NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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